



40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D T _C = +25°С
40V	2.5mΩ @ V _{GS} = 10V	100A
400	4mΩ @ V _{GS} = 4.5V	100A

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

- Engine management systems
- Body control electronics
- DC-DC converters

Features

- Rated to +175°C ideal for high ambient temperature environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low R_{DS(ON)} minimizes power losses
- Low Qg minimizes switching losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (DMTH4004LPSQ)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208

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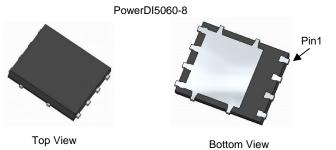
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Weight: 0.097 grams (Approximate)

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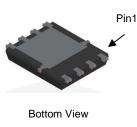
Internal Schematic

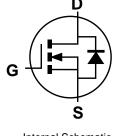


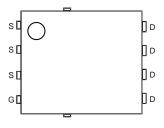
Site 2:

PowerDI5060-8/SWP (Type UX)









Top View

Pin Configuration

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ΠD

ΠD

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Internal Schematic

Top View Pin Configuration

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

G

<1000ppm antimony compounds.

Site 1:

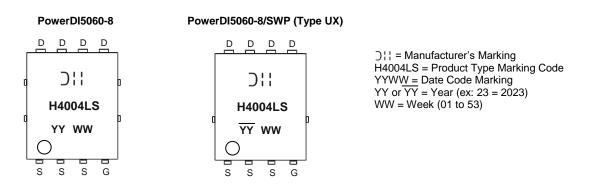


Ordering Information (Note 4)

Part Number	Paakana	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4004LPS-13	PowerDI5060-8	2500	Tape & Reel	
DMTH4004LPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	40	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	26 21	A
Continuous Drain Current (Note 6)	T _C = +25°C T _C = +70°C (Note 8)	ID	100 100	A
Maximum Continuous Body Diode Forward Current (Note 6)		ls	70	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	100	A
Avalanche Current, L=0.2mH		las	33.3	A
Avalanche Energy, L=0.2mH		E _{AS}	110	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	47	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	138	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

Notes:



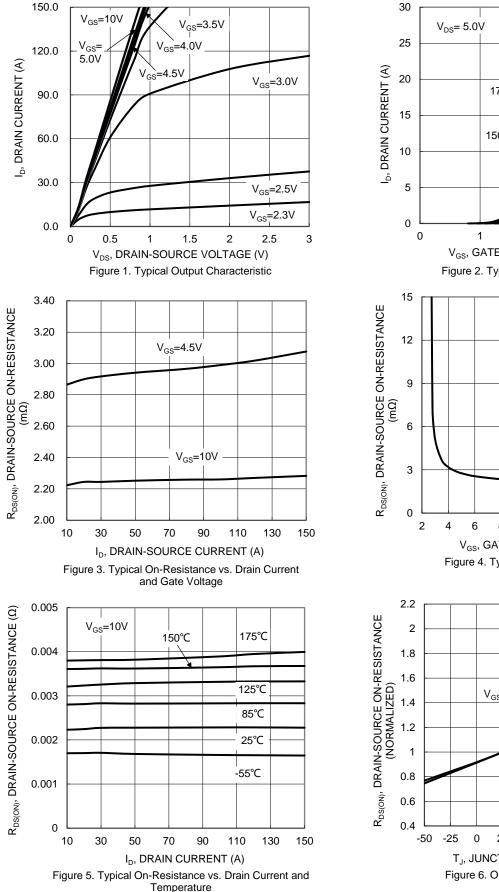
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			-			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			r	1		1
Drain-Source Breakdown Voltage	BVDSS	40	—	_	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_		1	μA	$V_{DS} = 32V$, $V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent		_	2.5	mΩ	Vgs = 10V, ID = 50A
Static Drain-Source On-Resistance	Rds(on)		—	4	11152	V _{GS} = 4.5V, I _D = 50A
Diode Forward Voltage	V _{SD}	—	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 50A$
DYNAMIC CHARACTERISTICS (Note 8)						*
Input Capacitance	Ciss		4508	—		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	—	1648	_	pF	
Reverse Transfer Capacitance	Crss		104	—		
Gate resistance	Rg	—	0.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	34.6	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	82.2	_		V _{DD} = 20V, I _D = 30A
Gate-Source Charge	Q _{gs}	_	9.9	_	nC	
Gate-Drain Charge	Q _{gd}	—	11.2	_		
Turn-On Delay Time	t _{D(ON)}	_	5.9	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 30A, R_G = 1.6\Omega$
Turn-On Rise Time	tR	_	13.3	_	ns	
Turn-Off Delay Time	td(OFF)		25.9			
Turn-Off Fall Time	tF		7.9	—	1	
Body Diode Reverse Recovery Time	trr		48.4		ns	
Body Diode Reverse Recovery Charge	Q _{RR}	_	72.4	—	nC	- I _F = 50A, di/dt = 100A/μs

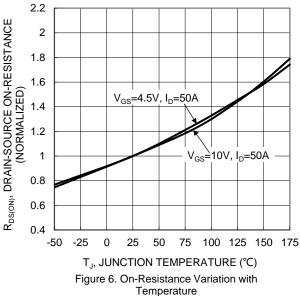
Notes:7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.



DMTH4004LPS



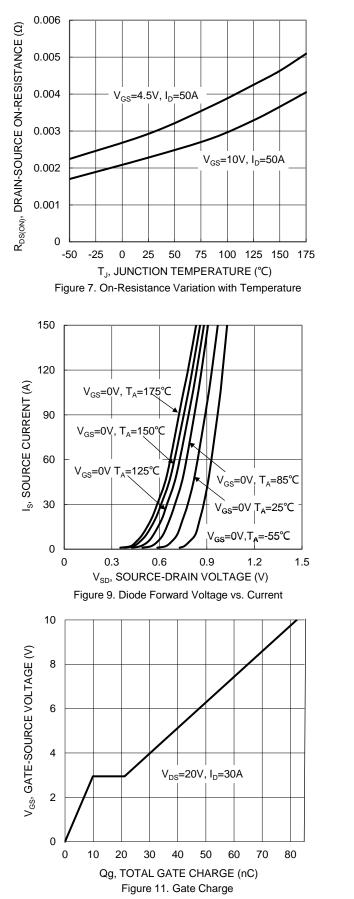
125°C 175°C 85 150°C 25 r -55°℃ 2 3 4 V_{GS}, GATE-SOURCE VOLTAGE (V) Figure 2. Typical Transfer Characteristic I_D=50A 8 10 12 16 18 20 14 V_{GS}, GATE-SOURCE VOLTAGE (V) Figure 4. Typical Transfer Characteristic



DMTH4004LPS Document number: DS37767 Rev.3 - 2



DMTH4004LPS



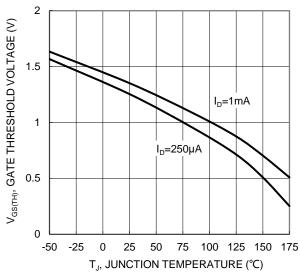
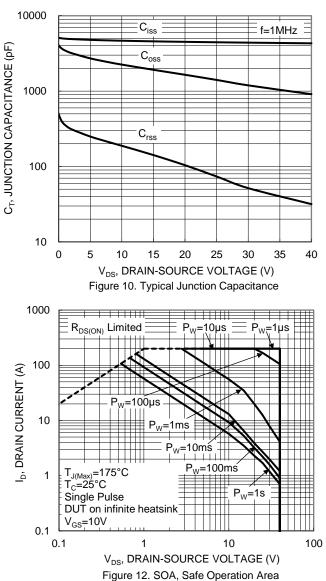
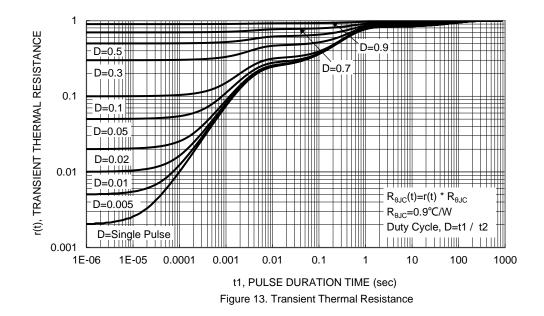


Figure 8. Gate Threshold Variation vs. Temperature





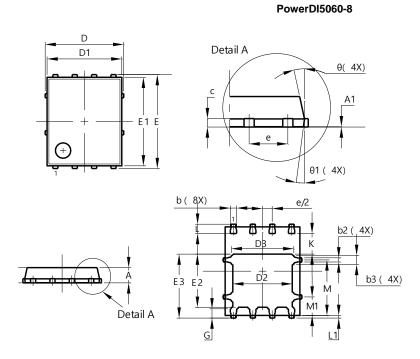




Package Outline Dimensions

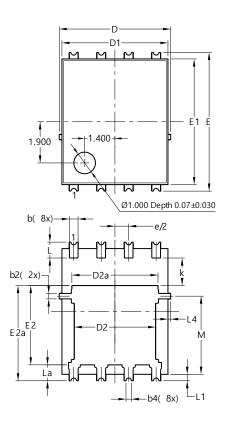
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

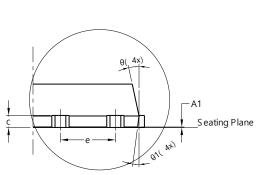


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C	0.230	0.330	0.277		
D	ļ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
ĸ	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
Μ	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
01	6°	8°	7°		
All Dimensions in mm					

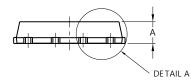
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



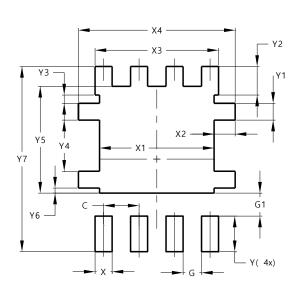
PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	0).25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	.40 BS0		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE		
L4	0.025	0.225	0.125	
Μ	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	All Dimensions in mm			



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

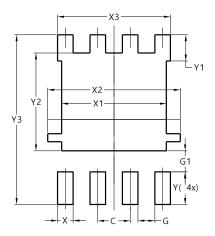


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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